2N4340, 2N4341 N-Channel JFET

Features

- InterFET N0016SH Geometry
- Low Noise: 4.2 nV/√Hz Typical
- High Gain: 3.1mS Typical (2N4341)
- RoHS Compliant
- SMT, TH, and Bare Die Package options.

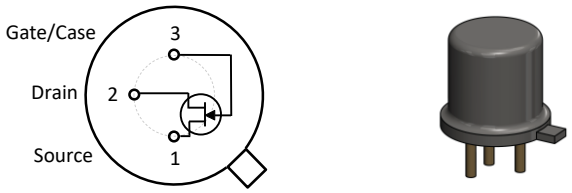
Applications

- Audio Amplifiers
- Small Signal Amplifier
- Ultrahigh Impedance Pre-Amplifier
- Voltage Controlled Resistor
- Current Limiters and Regulators

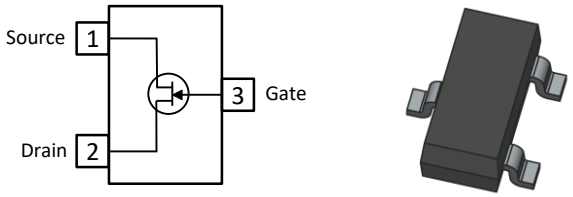
Description

The -50V InterFET 2N4340 and 2N4341 are targeted for sensitive amplifier stages for mid-frequencies designs. Gate leakages are typically less than 10pA at room temperatures. The TO-18 package is hermetically sealed and suitable for military applications.

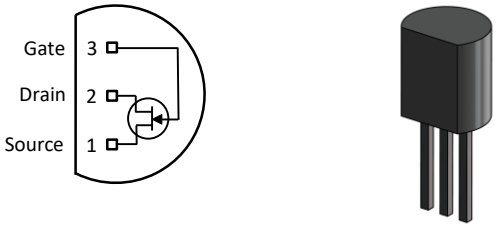
TO-18 Bottom View



SOT23 Top View



TO-92 Bottom View



Product Summary

Parameters		2N4340 Min	2N4341 Min	Unit
BV_{GSS}	Gate to Source Breakdown Voltage	-50	-50	V
I_{DSS}	Drain to Source Saturation Current	1.2	3	mA
$V_{GS(off)}$	Gate to Source Cutoff Voltage	-1	-2	V
G_{FS}	Forward Transconductance	1300	2000	µS

Ordering Information Custom Part and Binning Options Available

Part Number	Description	Case	Packaging
2N4340; 2N4341	Through-Hole	TO-18	Bulk
PN4340; PN4341	Through-Hole	TO-92	Bulk
SMP4340; SMP4341	Surface Mount	SOT23	Bulk
SMP4340TR; SMP4341TR	7" Tape and Reel: Max 3,000 Pieces 13" Tape and Reel: Max 9,000 Pieces	SOT23	Minimum 1,000 Pieces Tape and Reel
2N4340COT; 2N4341COT	Chip Orientated Tray (COT Waffle Pack)	COT	400/Waffle Pack
2N4340CFT; 2N4341CFT	Chip Face-up Tray (CFT Waffle Pack)	CFT	400/Waffle Pack

Electrical Characteristics

Maximum Ratings (@ T_A = 25°C, Unless otherwise specified)

Parameters		Value	Unit
V_{RGS}	Reverse Gate Source and Gate Drain Voltage	-50	V
I_{FG}	Continuous Forward Gate Current	50	mA
P_D	Continuous Device Power Dissipation	300	mW
P	Power Derating	2	mW/°C
T_J	Operating Junction Temperature	-55 to 125	°C
T_{STG}	Storage Temperature	-65 to 175	°C

Static Characteristics (@ TA = 25°C, Unless otherwise specified)

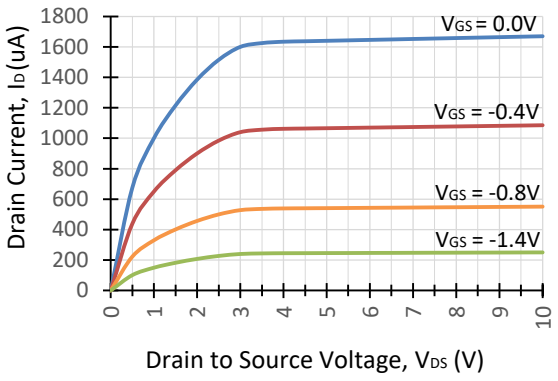
Parameters		Conditions	2N4340		2N4341		Unit
			Min	Max	Min	Max	
$V_{(BR)GSS}$	Gate to Source Breakdown Voltage	V_{DS} = 0V, I_G = -1µA	-50		-50		V
I_{GSS}	Gate to Source Reverse Current	V_{GS} = -30V, V_{DS} = 0V, T_A = 25°C V_{GS} = -30V, V_{DS} = 0V, T_A = 150°C		-0.1 -100		-0.1 -100	nA
$V_{GS(OFF)}$	Gate to Source Cutoff Voltage	V_{DS} = 15V, I_D = 0.1µA	-1	-3	-2	-6	V
I_{DSS}	Drain to Source Saturation Current	V_{GS} = 0V, V_{DS} = 15V (Pulsed)	1.2	3.6	3	9	mA
$I_{D(OFF)}$	Drain Cutoff Current	V_{DS} = 15V, V_{GS} = ( )		0.05 (-5)		0.07 (-10)	nA V

Dynamic Characteristics (@ TA = 25°C, Unless otherwise specified)

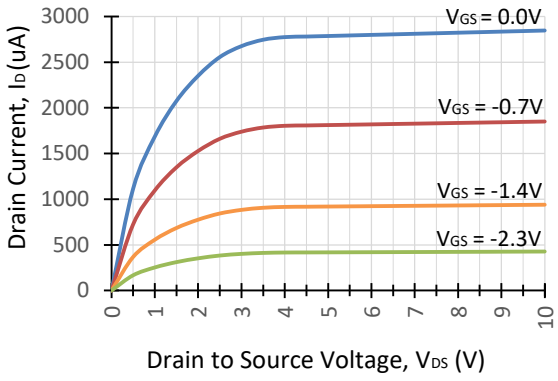
Parameters		Conditions	2N4340		2N4341		Unit
			Min	Max	Min	Max	
G_{FS}	Forward Transconductance	V_{DS} = 15V, V_{GS} = 0V, f = 1kHz	1300	3000	2000	4000	µS
G_{OS}	Output Conductance	V_{DS} = 15V, V_{GS} = 0V, f = 1kHz		30		60	µS
$R_{DS(ON)}$	Drain to Source ON Resistance	V_{GS} = 0V, I_D = 0A, f = 1kHz		1500		800	Ω
C_{iss}	Input Capacitance	V_{DS} = 15V, V_{GS} = 0V, f = 1MHz		7		7	pF
C_{rss}	Reverse Transfer Capacitance	V_{DS} = 15V, V_{GS} = 0V, f = 1MHz		3		3	pF
NF	Noise Figure	V_{DS} = 15V, V_{GS} = 0V, f = 1kHz R_G = 1 MΩ, BW = 200 Hz		1		1	dB

Typical 2N4340, 2N4341 Characteristics

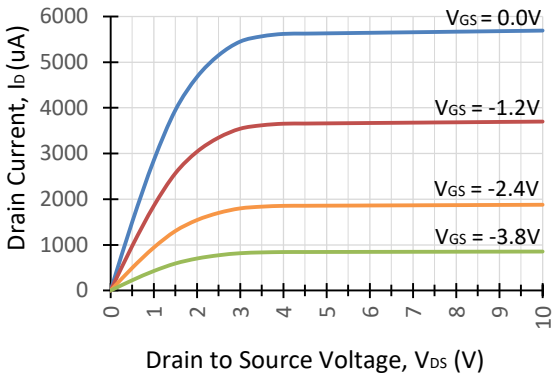
Typical Output @ $V_{GS(OFF)}$ = -1.5V



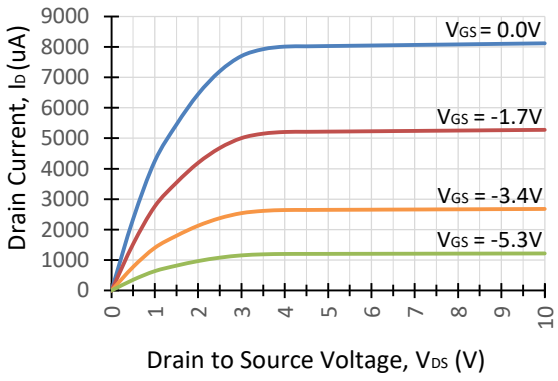
Typical Output @ $V_{GS(OFF)}$ = -2.5V



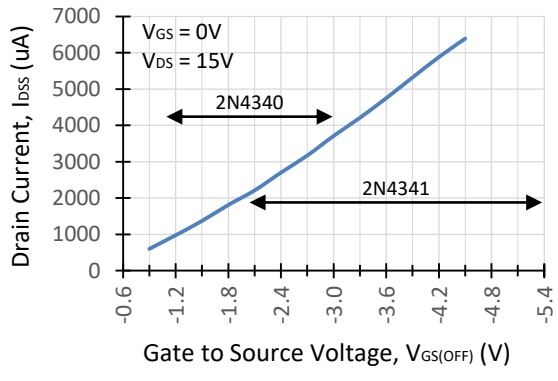
Typical Output @ $V_{GS(OFF)}$ = -4.0V



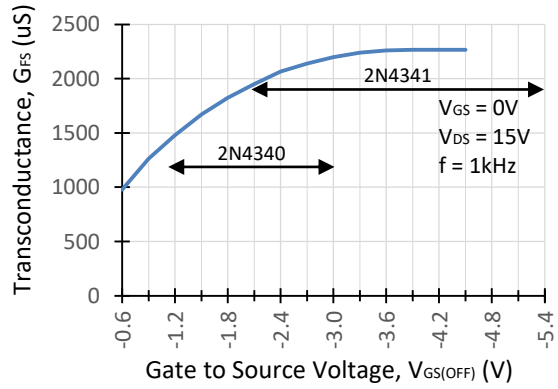
Typical Output @ $V_{GS(OFF)}$ = -5.5V



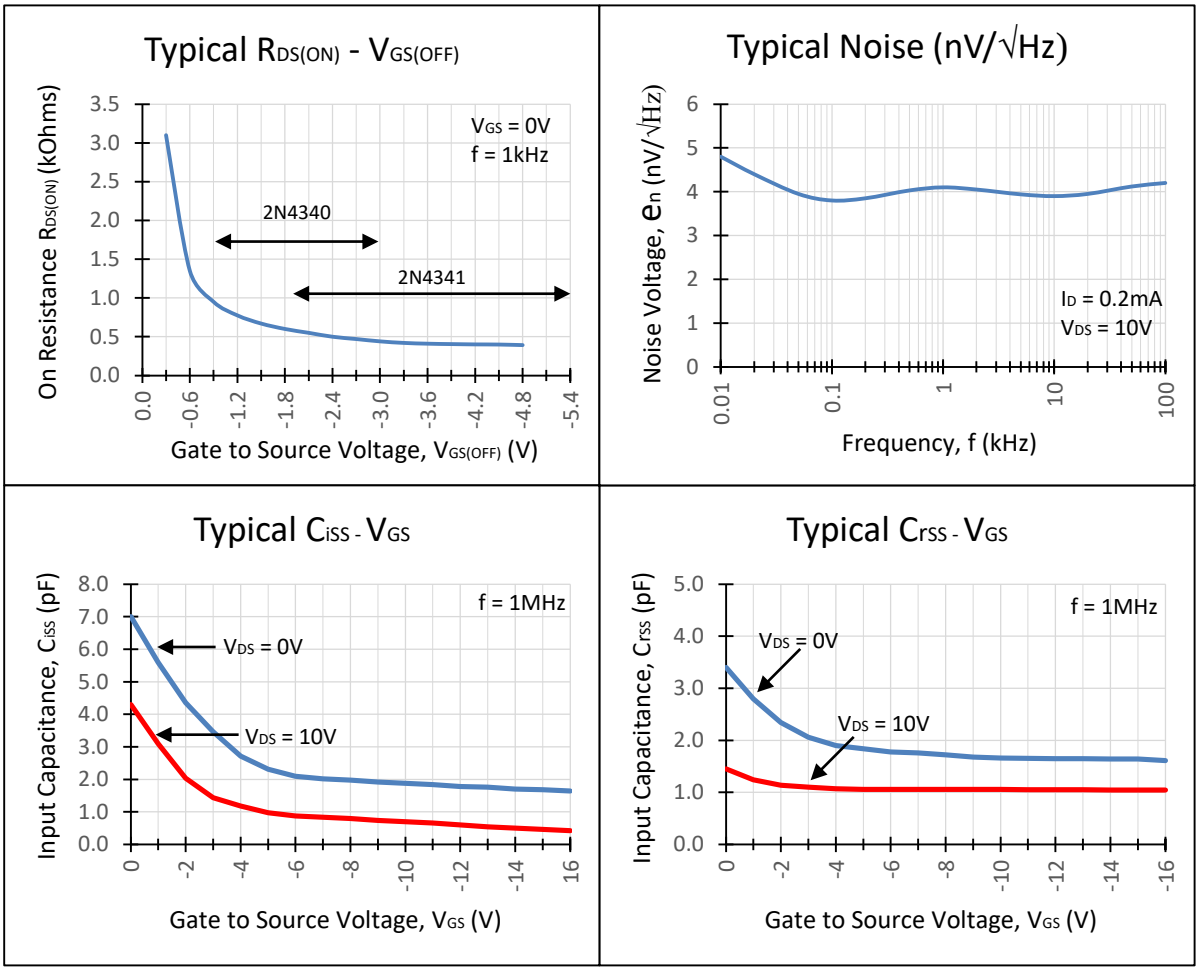
Typical I_{DSS} - $V_{GS(OFF)}$



Typical G_{FS} - $V_{GS(OFF)}$

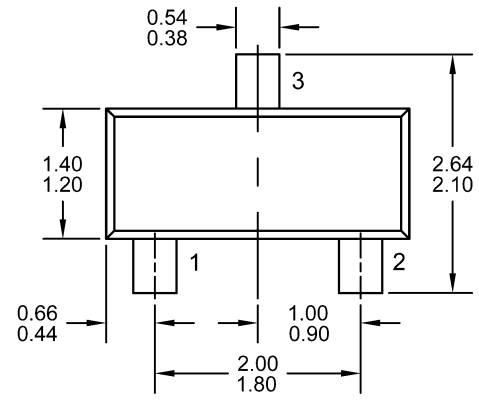


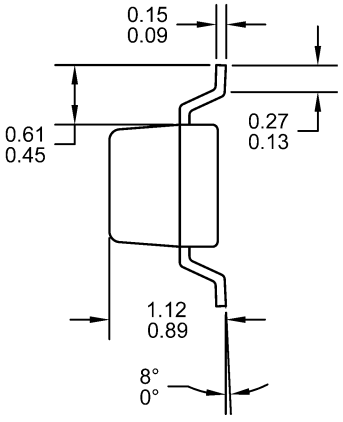
Typical 2N4340, 2N4341 Characteristics (Continued)

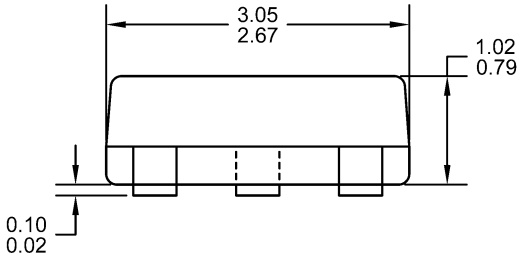


SOT23 (TO-236AB) Mechanical and Layout Data

Package Outline Data

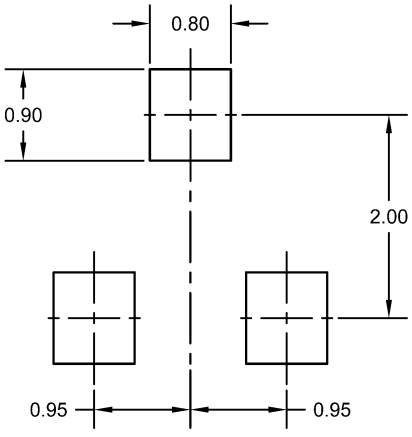






1. All linear dimensions are in millimeters.
2. Package weight approximately 0.12 grams
3. Molded plastic case UL 94V-0 rated
4. For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
5. Bulk product is shipped in standard ESD shipping material
6. Refer to JEDEC standards for additional information.

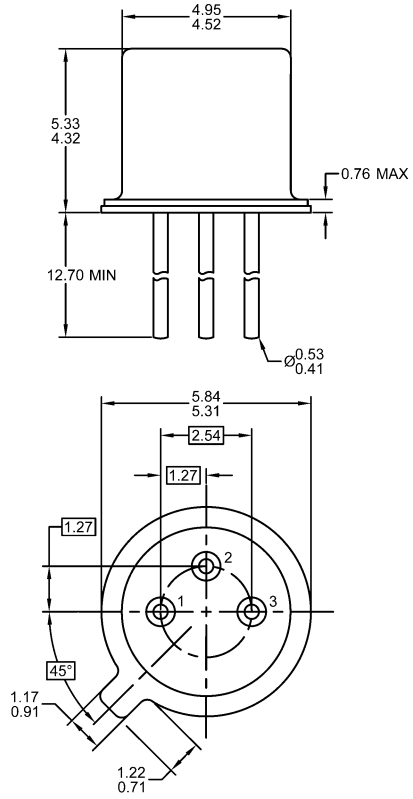
Suggested Pad Layout



1. All linear dimensions are in millimeters.
2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.

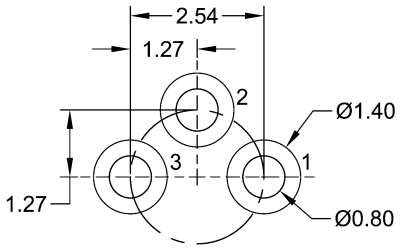
TO-18 Mechanical and Layout Data

Package Outline Data



1. All linear dimensions are in millimeters.
2. Package weight approximately 0.29 grams
3. Bulk product is shipped in standard ESD shipping material
4. Refer to JEDEC standards for additional information.

Suggested Through-Hole Layout



1. All linear dimensions are in millimeters.
2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.